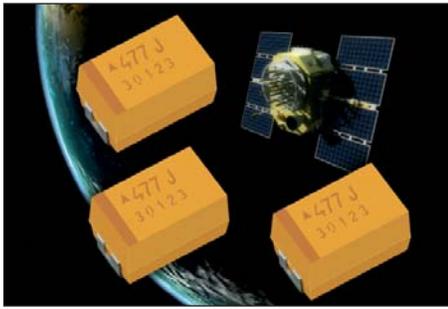


TBM Multianode



Tantalum Ultra Low ESR Space Level



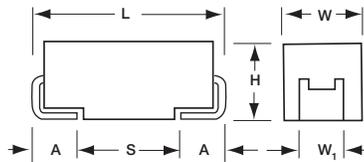
TBM Space Level series is screened to SRC9000 and utilizes an internal multi-anode design to achieve ultra-low ESR which improves performance in high ripple power application.

TBM Space Level is available with Weibull Grade "C" reliability and MIL-PRF-55365 Rev. G surge test option "C".

There are four termination finishes available: solder plated, fused solder plated, hot solder dipped and gold plated (these correspond to "H", "K", "C" and "B" termination, respectively, per MIL-PRF-55365).

The molding compound has been selected to meet the requirements of UL94V-0 (Flame Retardancy) and outgassing requirements of ASTM E-595.

For moisture sensitivity levels please refer to the High Reliability Tantalum MSL section located in the back of the High Reliability Tantalum Catalog.



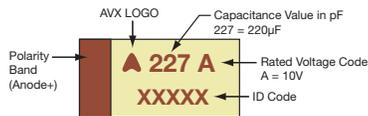
CASE DIMENSIONS: millimeters (inches)

Code	L±0.20 (0.008)	W+0.20 (0.008) -0.10 (0.004)	H+0.20 (0.008) -0.10 (0.004)	W ₁ ±0.20 (0.008)	A+0.30 (0.012) -0.20 (0.008)	S Min.
D	7.30 (0.287)	4.30 (0.169)	2.90 (0.114)	2.40 (0.094)	1.30 (0.051)	4.40 (0.173)
E	7.30 (0.287)	4.30 (0.169)	4.10 (0.162)	2.40 (0.094)	1.30 (0.051)	4.40 (0.173)

W₁ dimension applies to the termination width for A dimensional area only.

MARKING

D, E CASE



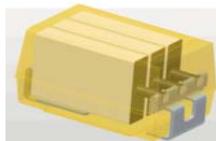
CAPACITANCE AND RATED VOLTAGE RANGE LETTER DENOTES CASE SIZE ESR LIMIT IN BRACKETS

Capacitance		Rated Voltage DC (V _R) to 85°C								
µF	Code	2.5V (e)	4V (G)	6V (J)	10V (A)	12V (B)	16V (C)	20V (D)	25V (E)	35V (V)
22	226									D(70) E(60,100)
33	336								D(65)	E(50,65)
47	476								E(65)	
68	686									
100	107							E(35,45)		
150	157						E(30,40)			
220	227				D(35)	E(35)				
330	337		D(35)	D(35)	E(35)					
470	477		D(35)	E(30)						
680	687		E(23)							
1000	108	D(25)	E(23)							
1500	158	E(18)								

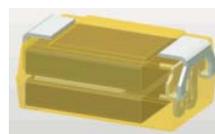
Available Ratings: ESR limits quoted in brackets (mOhms)

Notes: Voltage ratings are minimum values. AVX reserves the right to supply higher ratings in the same case size, to the same reliability standards. EIA standards for Low ESR solid tantalum capacitors allow an ESR movement of 1.25 times initial limit post mounting.

MULTIANODE CONSTRUCTION



MULTIANODE TBM D LOW SELF INDUCTANCE CONSTRUCTION "MIRROR" DESIGN



TBM Multianode



Tantalum Ultra Low ESR Space Level

HOW TO ORDER

SPACE LEVEL OPTIONS TO SRC9000:

TBM	E	477	*	006	L	□	L	@	9	^	++
Type	Case Size	Capacitance Code	Capacitance Tolerance	Voltage Code	Standard or Low ESR Range	Packaging	Inspection Level	Reliability Grade	Qualification Level	Termination Finish	Surge Test Option
		pF code: 1st two digits represent significant figures 3rd digit represents multiplier (number of zeros to follow)	M = ±20% K = ±10%	002 = 2.5Vdc 004 = 4Vdc 006 = 6Vdc 010 = 10Vdc 012 = 12Vdc 016 = 16Vdc 020 = 20Vdc 025 = 25Vdc 035 = 35Vdc	C = Std ESR L = Low ESR	B = Bulk R = 7" T&R S = 13" T&R W = Waffle See page 8 for additional packaging options.	L = Group A	Weibull: C = 0.01%/1000 hrs. 90% conf.	9 = SRC9000	H = Solder Plated 0 = Fused Solder Plated 8 = Hot Solder Dipped 9 = Gold Plated	45 = 10 cycles, -55°C & +85°C before Weibull
  <p>For RoHS compliant products, please select correct termination style.</p>											

TECHNICAL SPECIFICATIONS

Technical Data: Unless otherwise specified, all technical data relate to an ambient temperature of +25°C

Capacitance Range:	22 µF to 1500 µF										
Capacitance Tolerance:	±10%; ±20%										
Rated Voltage DC (V_R)	≤ +85°C:	2.5	4	6	10	12	16	20	25	35	
Category Voltage (V_C)	≤ +125°C:	1.7	2.7	4	7	8.4	10	13	17	23	
Surge Voltage (V_S)	≤ +85°C:	3.3	5.2	8	13	15.6	20	26	32	46	
Surge Voltage (V_S)	≤ +125°C:	2.2	3.4	5	8	9.6	12	16	20	28	
Temperature Range:	-55°C to +125°C										

TBM Multianode



Tantalum Ultra Low ESR Space Level

RATING & PART NUMBER REFERENCE		Parametric Specifications by Rating									Typical RMS Ripple Data by Rating						
		Cap @ 120Hz µF @ 25°C	DC Rated Voltage V @ +85°C	ESR @ 100kHz mOhms @ +25°C	DCL max			DF max			Power Dissipation W	25°C Ripple A (100kHz)	85°C Ripple A (100kHz)	125°C Ripple A (100kHz)	25°C Ripple V (100kHz)	85°C Ripple V (100kHz)	125°C Ripple V (100kHz)
					+25°C (µA)	+85°C (µA)	+125°C (µA)	+25°C (%)	+85°C (%)	+125°C (%)							
AVX P/N	Case																
2.5 Volt @ 85°C (1.7 Volt @ 125°C)																	
TBMD108*002L□LC9^45	D	1000	2.5	25	18.8	188	376	8	11	12	0.255	3.194	2.874	1.277	0.080	0.072	0.032
TBME158*002C□LC9^45	E	1500	2.5	18	28.1	281	562	6	9	10	0.270	3.873	3.486	1.549	0.070	0.063	0.028
4 Volt @ 85°C (2.7 Volt @ 125°C)																	
TBMD337*004L□LC9^45	D	330	4	35	9.9	99	198	8	11	12	0.255	2.699	2.429	1.080	0.094	0.085	0.038
TBMD477*004L□LC9^45	D	470	4	35	14.1	141	282	8	11	12	0.255	2.699	2.429	1.080	0.094	0.085	0.038
TBME687*004C□LC9^45	E	680	4	23	20.4	204	408	6	9	10	0.270	3.426	3.084	1.370	0.079	0.071	0.032
TBME108*004C□LC9^45	E	1000	4	23	30	300	600	6	9	10	0.270	3.426	3.084	1.370	0.079	0.071	0.032
6 Volt @ 85°C (4 Volt @ 125°C)																	
TBMD337*006L□LC9^45	D	330	6	35	14.9	149	298	8	11	12	0.255	2.699	2.429	1.080	0.094	0.085	0.038
TBME477*006C□LC9^45	E	470	6	30	21.2	212	424	6	9	10	0.270	3.000	2.700	1.200	0.090	0.081	0.036
10 Volt @ 85°C (7 Volt @ 125°C)																	
TBMD227*010L□LC9^45	D	220	10	35	16.5	165	330	8	11	12	0.255	2.699	2.429	1.080	0.094	0.085	0.038
TBME337*010C□LC9^45	E	330	10	35	24.8	248	496	6	9	10	0.270	2.777	2.500	1.111	0.097	0.087	0.039
12 Volt @ 85°C (8.4 Volt @ 125°C)																	
TBME227*012C□LC9^45	E	220	12	35	19.8	198	396	6	9	10	0.270	2.777	2.500	1.111	0.097	0.087	0.039
16 Volt @ 85°C (10 Volt @ 125°C)																	
TBME157*016L□LC9^45	E	150	16	30	18	180	360	6	9	10	0.270	3.000	2.700	1.200	0.090	0.081	0.036
TBME157*016C□LC9^45	E	150	16	40	18	180	360	6	9	10	0.270	2.598	2.338	1.039	0.104	0.094	0.042
20 Volt @ 85°C (13 Volt @ 125°C)																	
TBME107*020L□LC9^45	E	100	20	35	15	150	300	6	9	10	0.270	2.777	2.500	1.111	0.097	0.087	0.039
TBME107*020C□LC9^45	E	100	20	45	15	150	300	6	9	10	0.270	2.449	2.205	0.980	0.110	0.099	0.044
25 Volt @ 85°C (17 Volt @ 125°C)																	
TBMD336*025L□LC9^45	D	33	25	65	6.2	62	124	8	11	12	0.255	1.981	1.783	0.792	0.129	0.116	0.051
TBME476*025L□LC9^45	E	47	25	65	8.8	88	176	6	9	10	0.270	2.038	1.834	0.815	0.132	0.119	0.053
35 Volt @ 85°C (23 Volt @ 125°C)																	
TBMD226*035L□LC9^45	D	22	35	70	5.8	58	116	8	11	12	0.255	1.909	1.718	0.763	0.134	0.120	0.053
TBME226*035L□LC9^45	E	22	35	60	5.8	58	116	6	9	10	0.270	2.121	1.909	0.849	0.127	0.115	0.051
TBME226*035C□LC9^45	E	22	35	100	5.8	58	116	6	9	10	0.270	1.643	1.479	0.657	0.164	0.148	0.066
TBME336*035L□LC9^45	E	33	35	50	8.7	87	174	6	9	10	0.270	2.324	2.091	0.930	0.116	0.105	0.046
TBME336*035C□LC9^45	E	33	35	65	8.7	87	174	6	9	10	0.270	2.038	1.834	0.815	0.132	0.119	0.053

All technical data relates to an ambient temperature of +25°C. Capacitance and DF are measured at 120Hz, 0.5V RMS with a maximum DC bias of 2.2 volts. DCL is measured at rated voltage after 5 minutes.

NOTE: AVX reserves the right to supply a higher voltage rating or tighter tolerance part in the same case size, to the same reliability standards.